
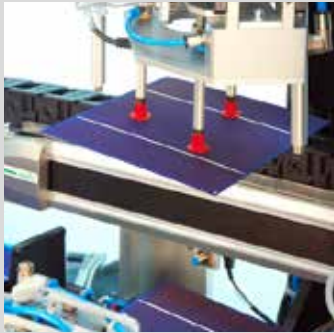


VISOR® Solar sensor for inspecting solar cells

Focusing on what matters



 made in Germany



The VISOR® Solar sensor operates accurately and reliably even in fast-cycle processes.



The VISOR® Solar sensor measures every wafer or cell and thus detects even minimal edge breakouts.

HIGHLIGHTS OF VISOR® SOLAR SENSOR

- Simple integration
- Precise position detection
- Detection of Edge defects
- Detection of holes
- Transport belts can be masked via software
- Short cycle time from 60 ms
- Reliable operation, even in daylight
- No backlight necessary
- Low space requirement: operating distance from 360 mm

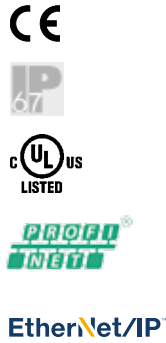
SensoPart has expanded its range of vision sensors with the VISOR® Solar in order to combat rising cost pressure in the production of solar cells. The compact sensor detects the position and any damage to wafers and cells. It allows robots to pick up and lay down wafers accurately. Wafers and solar cells with fine breakouts can be directly rejected during this step, before they can completely break up and damage other material.

These sensors can also be integrated in existing lines – as easily as a light barrier. Before a cell is printed, the sensor checks it for damage that could lead to breakage during the print process, preventing costly machine breakdowns.

VISOR® Solar sensor – Product Overview					
	Firmware Option	Resolution	Focal length	Integrated illumination	Page
V20-SO-A2-xxx	Advanced	1280 x 1024 pixels	12 mm	White, red or infrared LEDs	134
V20-SO-A2-xxx	Advanced	1280 x 1024 pixels	C-mount	None	136
V10-SO-S1-xxx	Standard	736 x 480 pixels	6 mm	White LEDs	138
V10-SO-A1-xxx	Advanced	736 x 480 pixels	6 mm	White or infrared LEDs	140
V10-SO-A1-xxx	Advanced	736 x 480 pixels	12 mm	White or infrared LEDs	142
V10-SO-A1-xxx	Advanced	736 x 480 pixels	C-mount	None	144

VISOR® V20 Solar sensor

Advanced vision sensor for wafer and cell inspection, 12 mm



PRODUCT HIGHLIGHTS

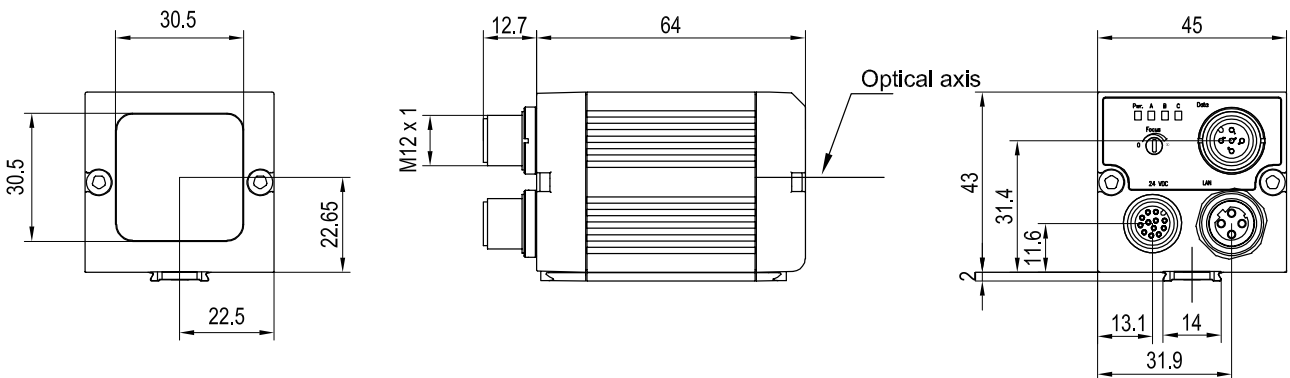
- Automatic detection of wafer and cell geometry
- Suitable for frontlit and backlit applications
- Simple sensor optimisation regarding evaluation speed and test precision (sub-pixel process)
- Detection of holes/cracks and breakouts
- Distortion correction
- Examination and position detection of busbars

Optical data		Functions	
Resolution	1280 x 1024 pixels	Number of jobs / detectors	max. 255 / max. 255
CMOS	1/1.8", monochrome	Detectors	Wafers, pattern comparison, contrast, brightness, grey level, calliper
Integrated lens, focal length	12 mm, adjustable focal position	Properties	Position tracking; Wafers incl. busbars: localisation of wafers or busbars and examination of wafers; Calliper: distance between edges; Pattern comparison: teach-in and detection of patterns grey threshold, brightness: evaluation of brightness; contrast: evaluation of contrast
Adjustment range	30 mm to infinity	Typical cycle times ²	Typ. 100 ms wafer Typ. 8 ms calliper Typ. 20 ms pattern comparison Typ. 2 ms brightness Typ. 2 ms contrast Typ. 2 ms grey threshold
Integrated illumination	White, red, infrared LEDs		
Minimum field of view, X x Y	16 x 13 mm ²		
Electrical data		Mechanical data	
Operating voltage, +U _B	18 ... 26.4 V DC ¹	Dimensions	65 x 45 x 45 mm (without plug)
Current consumption (without illumination and I/O)	≤ 120 mA	Enclosure rating	IP 67
Current consumption (without I/O)	≤ 200 mA	Material, housing	Aluminium, plastic
Protective circuits	Reverse-polarity protection, U _B / short-circuit protection of all outputs	Material, front screen	Plastic
Power On Delay	Ca. 13 s after Power on	Ambient temperature: operation	0 ... +50° C ³
Outputs	PNP / NPN (switchable)	Ambient temperature: storage	-20 ... +60° C ³
Max. output current (per output)	50 mA, 100 mA (pin 12)	Weight	Ca. 160 g
Inputs	PNP/NPN High > U _B -1 V, Low < 3 V	Plug connections	Supply and I/O M12, 12-pin Ethernet M12, 4-pin Data M12, 5-pin
Input resistance	> 20 kOhm	Vibration and impact resistance	EN 60947-5-2
Encoder input	High > 4V		
Interfaces	Ethernet (LAN), RS422, RS232, EtherNet/IP, PROFINET, SensoWeb		
Inputs/outputs	2 inputs, 4 outputs, 4 selectable inputs/outputs		

¹ Max. ripple < 5 V_{SS} ² with VGA-resolution (640 x 480 pixels) ³ 80 % air humidity, non-condensing

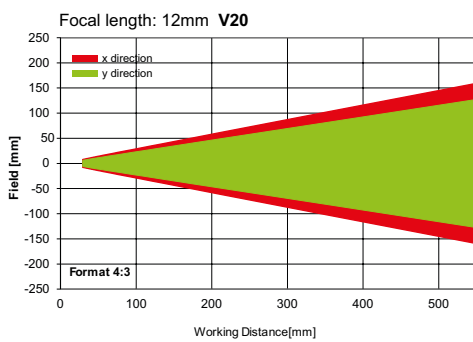
Illumination	Part number	Article number
White	V20-SO-A2-W12	536-91028
Red	V20-SO-A2-R12	536-91029
Infrared	V20-SO-A2-I12	536-91030

VISOR® vision sensor



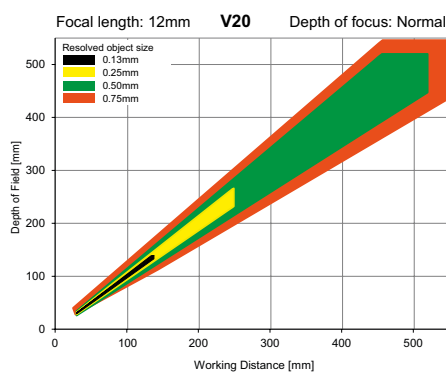
153-00911

Field of view



155-01637

Depth of field: normal



155-01636

Accessories

Connection cables	From Page A-38
Illumination	From Page A-30
Brackets	From Page A-14
Interface accessories	From Page A-42

VISOR® V20 Solar sensor

Advanced vision sensor for wafer and cell inspection, C-mount



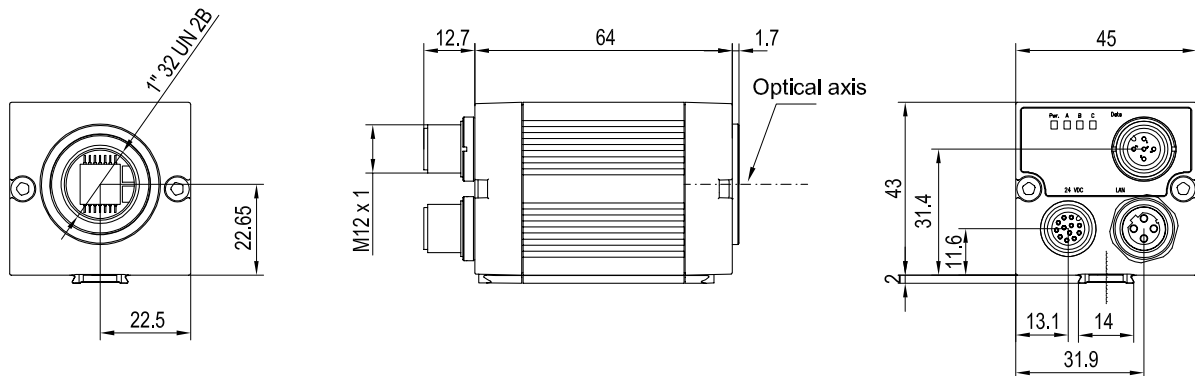
PRODUCT HIGHLIGHTS

- Automatic detection of wafer and cell geometry
- Suitable for frontlit and backlit applications
- Simple sensor optimisation regarding evaluation speed and test precision (sub-pixel process)
- Detection of holes/cracks and breakouts
- Distortion correction
- Examination and position detection of busbars

Optical data		Functions	
Resolution	1280 x 1024 pixels	Number of jobs / detectors	max. 255 / max. 255
CMOS	1/1.8", monochrome	Detectors	Wafers, pattern comparison, contrast, brightness, grey level, calliper
Integrated lens, focal length	C-Mount	Properties	Position tracking; Wafers incl. busbars: localisation of wafers or busbars and examination of wafers; Calliper: distance between edges; Pattern comparison: teach-in and detection of patterns grey threshold, brightness: evaluation of brightness; contrast: evaluation of contrast
Adjustment range	Dependent on lens	Typical cycle times ²	Typ. 100 ms wafer Typ. 8 ms calliper Typ. 20 ms pattern comparison Typ. 2 ms brightness Typ. 2 ms contrast Typ. 2 ms grey threshold
Integrated illumination	None		
Minimum field of view, X x Y	Dependent on lens		
Electrical data		Mechanical data	
Operating voltage, +U _B	18 ... 26.4 V DC ¹	Dimensions	65 x 45 x 45 mm (without plug)
Current consumption (without illumination and I/O)	≤ 120 mA	Enclosure rating	IP 65 ³
Current consumption (without I/O)	≤ 200 mA	Material, housing	Aluminium, plastic
Protective circuits	Reverse-polarity protection, U _B / short-circuit protection of all outputs	Material, front screen	Plastic
Power On Delay	Ca. 13 s after Power on	Ambient temperature: operation	0 ... +50 °C ⁴
Outputs	PNP / NPN (switchable)	Ambient temperature: storage	-20 ... +60 °C ⁴
Max. output current (per output)	50 mA, 100 mA (pin 12)	Weight	Ca. 160 g
Inputs	PNP/NPN High > U _B -1 V, Low < 3 V	Plug connections	Supply and I/O M12, 12-pin Ethernet M12, 4-pin Data M12, 5-pin
Input resistance	> 20 kOhm	Vibration and impact resistance	EN 60947-5-2
Encoder input	High > 4V		
Interfaces	Ethernet (LAN), RS422, RS232, EtherNet/IP, PROFINET, SensoWeb		
Inputs/outputs	2 inputs, 4 outputs, 4 selectable inputs/outputs		

¹ Max. ripple < 5 V_{SS} ² With VGA-resolution (640 x 480 Pixel) ³ With LPT45 C-mount protective casing ⁴ 80 % air humidity, non-condensing

Part number	Article number
V20-SO-A2-C	536-91031

VISOR® vision sensor


153-00912

4

Lens

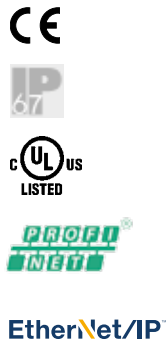

	LO C 8	LO C 12	LO C 16	LO C 25	LO C 35	LO C 50	LO C 75
Focal length	8 mm	12 mm	16 mm	25 mm	35 mm	50 mm	75 mm
Article number	526-51513	526-51514	526-51515	526-51516	526-51525	526-51113	526-51116

Accessories

Connection cables	From Page A-38
Illumination	From Page A-30
Lenses	From Page A-27
Brackets	From Page A-14
Interface accessories	From Page A-42

VISOR® V10 Solar sensor

Standard vision sensor for wafer and cell inspection, 6 mm



PRODUCT HIGHLIGHTS

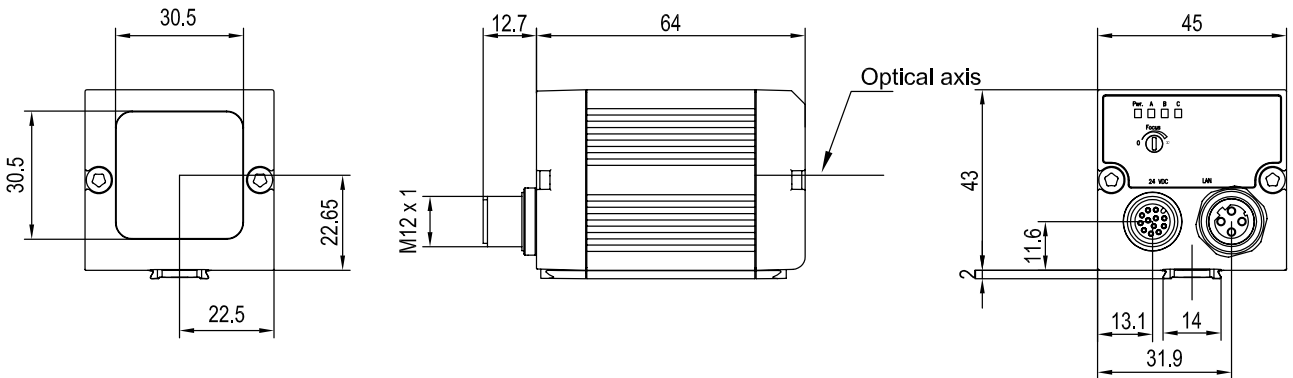
- Automatic detection of wafer and cell geometry
- Suitable for frontlit and backlit applications
- Simple sensor optimisation regarding evaluation speed and test precision (sub-pixel process)
- Detection of holes/cracks and breakouts
- Distortion correction

Optical data		Functions	
Resolution	736 x 480 pixels	Number of jobs / detectors	8 / 32
CMOS	1/3", monochrome	Detectors	Wafers, contrast, brightness, grey level
Integrated lens, focal length	6 mm, adjustable focal position	Properties	Wafers: localisation and examination of wafers Grey threshold, brightness: evaluation of brightness Contrast: evaluation of contrast
Adjustment range	6 mm to infinity	Typical cycle times	Typ. 100 ms wafer Typ. 2 ms brightness Typ. 2 ms contrast Typ. 2 ms grey threshold
Integrated illumination	White LEDs		
Minimum field of view, X x Y	5 x 4 mm ²		
Electrical data		Mechanical data	
Operating voltage, +U _b	18 ... 26.4 V DC ¹	Dimensions	65 x 45 x 45 mm (without plug)
Current consumption (without illumination and I/O)	≤ 120 mA	Enclosure rating	IP 67
Current consumption (without I/O)	≤ 200 mA	Material, housing	Aluminium, plastic
Protective circuits	Reverse-polarity protection, U _b / short-circuit protection of all outputs	Material, front screen	Plastic
Power On Delay	Ca. 13 s after Power on	Ambient temperature: operation	0 ... +50 °C ²
Outputs	PNP / NPN (switchable)	Ambient temperature: storage	-20 ... +60 °C ²
Max. output current (per output)	50 mA, 100 mA (pin 12)	Weight	Ca. 160 g
Inputs	PNP/NPN High > U _b -1 V, Low < 3 V	Plug connections	Supply and I/O M12, 12-pin Ethernet M12, 4-pin
Input resistance	> 20 kOhm	Vibration and impact resistance	EN 60947-5-2
Interfaces	Ethernet (LAN), EtherNet/IP, PROFINET, SensoWeb		
Inputs/outputs	2 inputs, 4 outputs, 2 selectable inputs/outputs		

¹ Max. ripple < 5V_{SS} ² 80 % air humidity, non-condensing

Illumination	Depth of field	Part number	Article number
White	Normal	V10-SO-S1-W6	535-91049

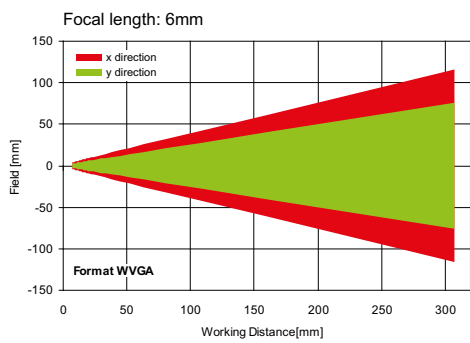
VISOR® vision sensor



153-01030

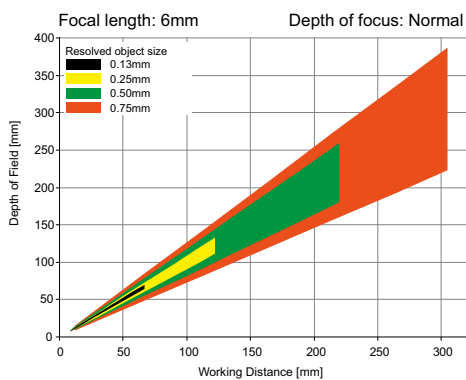
4

Field of view



155-01422

Depth of field: normal



155-01409

Accessories

Connection cables	From Page A-38
Illumination	From Page A-30
Brackets	From Page A-14
Interface accessories	From Page A-42

VISOR® V10 Solar sensor

Advanced vision sensor for wafer and cell inspection, 6 mm



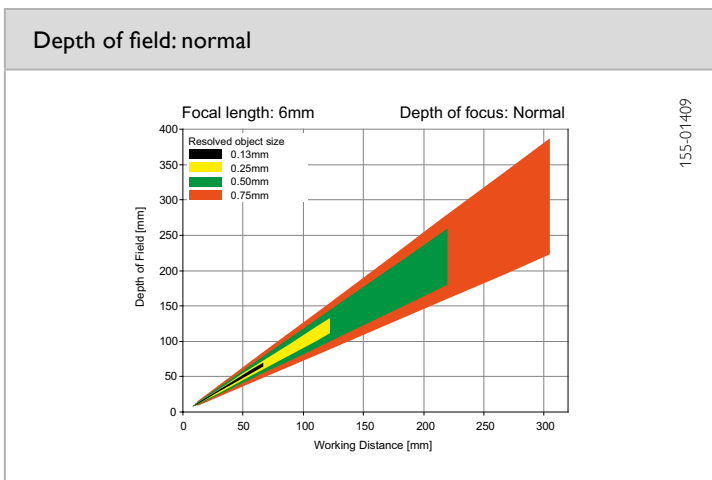
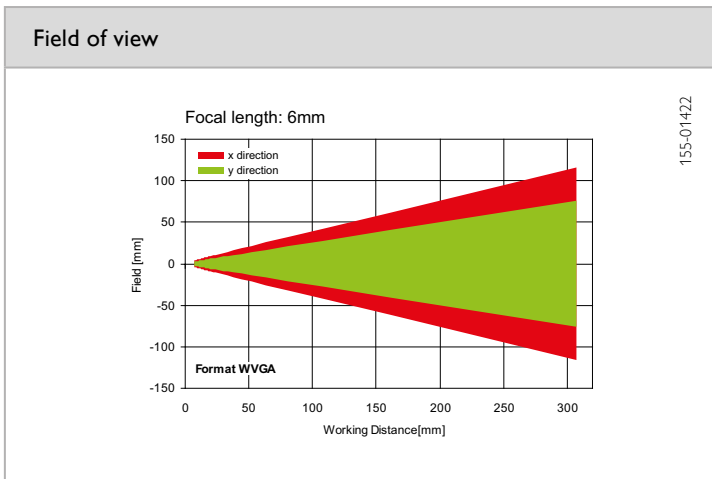
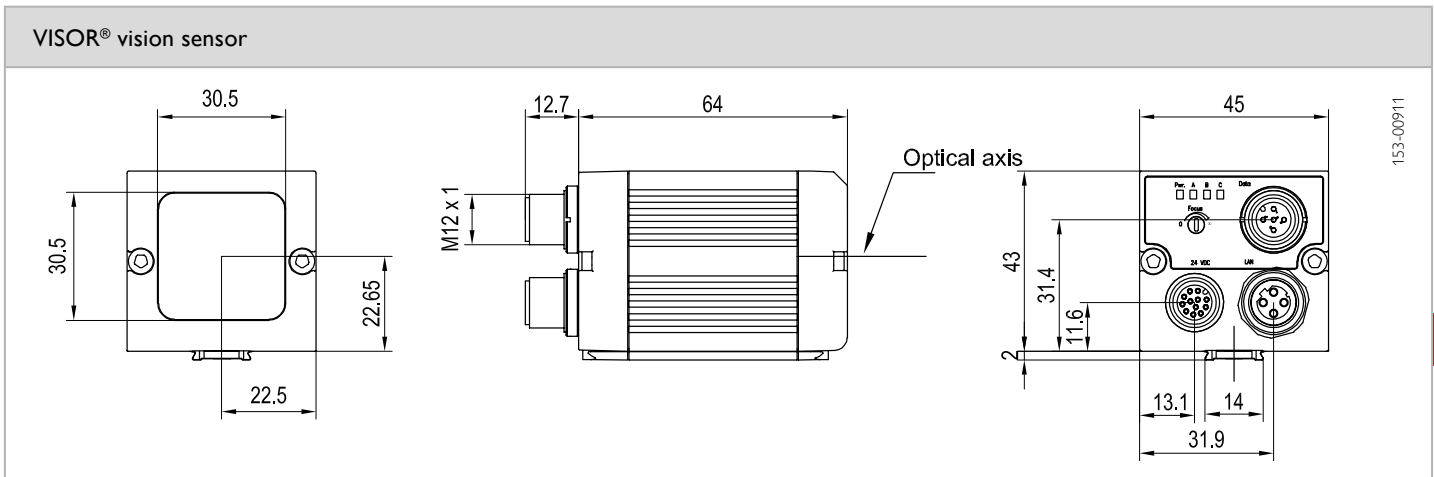
PRODUCT HIGHLIGHTS

- Automatic detection of wafer and cell geometry
- Suitable for frontlit and backlit applications
- Simple sensor optimisation regarding evaluation speed and test precision (sub-pixel process)
- Detection of holes/cracks and breakouts
- Distortion correction
- Examination and position detection of busbars

Optical data		Functions	
Resolution	736 x 480 pixels	Number of jobs / detectors	max. 255 / max. 255
CMOS	1/3", monochrome	Detectors	Wafers, busbars, pattern comparison, contrast, brightness, grey level, calliper
Integrated lens, focal length	6 mm, adjustable focal position	Properties	Position tracking Wafers incl. busbars: localisation of wafers or busbars and examination of wafers; Calliper: distance between edges; Pattern comparison: teach-in and detection of patterns; Grey threshold, brightness: evaluation of brightness; Contrast: evaluation of contrast
Adjustment range	6 mm to infinity	Typical cycle times	Typ. 100 ms wafer Typ. 8 ms calliper Typ. 20 ms pattern comparison Typ. 2 ms brightness Typ. 2 ms contrast Typ. 2 ms grey threshold
Integrated illumination	White, infrared LEDs		
Minimum field of view, X x Y	5 x 4 mm ²		
Electrical data		Mechanical data	
Operating voltage, +U _B	18 ... 26.4V DC ¹	Dimensions	65 x 45 x 45 mm (without plug)
Current consumption (without illumination and I/O)	≤ 120 mA	Enclosure rating	IP 67
Current consumption (without I/O)	≤ 200 mA	Material, housing	Aluminium, plastic
Protective circuits	Reverse-polarity protection, U _B / short-circuit protection of all outputs	Material, front screen	Plastic
Power On Delay	Ca. 13 s after Power on	Ambient temperature: operation	0 ... +50 °C ²
Outputs	PNP / NPN (switchable)	Ambient temperature: storage	-20 ... +60 °C ²
Max. output current (per output)	50 mA, 100 mA (pin 12)	Weight	Ca. 160 g
Inputs	PNP/NPN High > U _B -1V, Low < 3V	Plug connections	Supply and I/O M12, 12-pin Ethernet M12, 4-pin Data M12, 5-pin
Input resistance	> 20 kOhm	Vibration and impact resistance	EN 60947-5-2
Encoder input	High > 4V		
Interfaces	Ethernet (LAN), RS422, EtherNet/IP, PROFINET, SensoWeb		
Inputs/outputs	2 inputs, 4 outputs, 4 selectable inputs/outputs		

¹ Max. ripple < 5V_{SS} ² 80 % air humidity, non-condensing

Illumination	Depth of field	Part number	Article number
White	Normal	V10-SO-A1-W6	535-91051
Infrared	Normal	V10-SO-A1-I6	535-91053

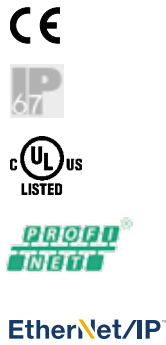


Accessories

Connection cables	From Page A-38
Illumination	From Page A-30
Brackets	From Page A-14
Interface accessories	From Page A-42

VISOR® V10 Solar sensor

Advanced vision sensor for wafer and cell inspection, 12 mm



PRODUCT HIGHLIGHTS

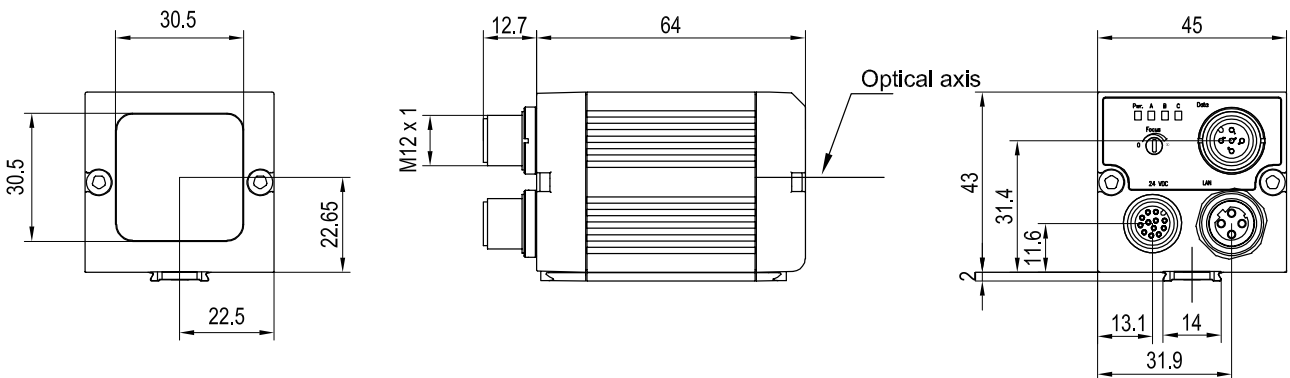
- Automatic detection of wafer and cell geometry
- Suitable for frontlit and backlit applications
- Simple sensor optimisation regarding evaluation speed and test precision (sub-pixel process)
- Detection of holes/cracks and breakouts
- Distortion correction
- Examination and position detection of busbars

Optical data		Functions	
Resolution	736 x 480 pixels	Number of jobs / detectors	max. 255 / max. 255
CMOS	1/3", monochrome	Detectors	Wafers, busbars, pattern comparison, contrast, brightness, grey level, calliper
Integrated lens, focal length	12 mm, adjustable focal position	Properties	Position tracking Wafers incl. busbars: localisation of wafers or busbars and examination of wafers; Calliper: distance between edges; Pattern comparison: teach-in and detection of patterns; Grey threshold, brightness: evaluation of brightness Contrast: evaluation of contrast
Adjustment range	30 mm to infinity	Typical cycle times	Typ. 100 ms wafer Typ. 8 ms calliper Typ. 20 ms pattern comparison Typ. 2 ms brightness Typ. 2 ms contrast Typ. 2 ms grey threshold
Integrated illumination	White, infrared LEDs		
Minimum field of view, X x Y	8 x 6 mm ²		
Electrical data		Mechanical data	
Operating voltage, +U _B	18 ... 26.4 V DC ¹	Dimensions	65 x 45 x 45 mm (without plug)
Current consumption (without illumination and I/O)	≤ 120 mA	Enclosure rating	IP 67
Current consumption (without I/O)	≤ 200 mA	Material, housing	Aluminium, plastic
Protective circuits	Reverse-polarity protection, U _B / short-circuit protection of all outputs	Material, front screen	Plastic
Power On Delay	Ca. 13 s after Power on	Ambient temperature: operation	0 ... +50 °C ²
Outputs	PNP / NPN (switchable)	Ambient temperature: storage	-20 ... +60 °C ²
Max. output current (per output)	50 mA, 100 mA (pin 12)	Weight	Ca. 160 g
Inputs	PNP/NPN High > U _B -1 V, Low < 3 V	Plug connections	Supply and I/O M12, 12-pin Ethernet M12, 4-pin Data M12, 5-pin
Input resistance	> 20 kOhm	Vibration and impact resistance	EN 60947-5-2
Encoder input	High > 4 V		
Interfaces	Ethernet (LAN), RS422, RS232, EtherNet/IP, PROFINET, SensoWeb		
Inputs/outputs	2 inputs, 4 outputs, 4 selectable inputs/outputs		

¹ Max. ripple < 5 V_{SS} ² 80 % air humidity, non-condensing

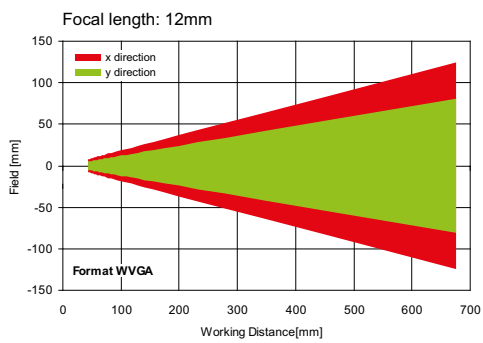
Illumination	Depth of field	Part number	Article number
White	Normal	V10-SO-A1-W12	535-91052
Infrared	Normal	V10-SO-A1-I12	535-91054

VISOR® vision sensor



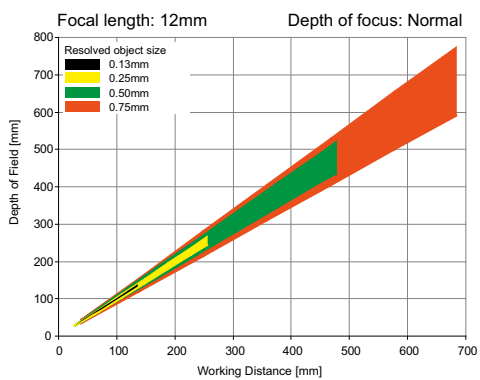
153-00911

Field of view



155-01423

Depth of field: normal



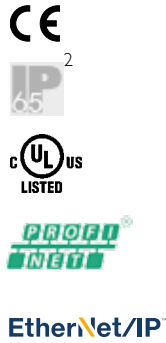
155-01410

Accessories

Connection cables	From Page A-38
Illumination	From Page A-30
Brackets	From Page A-14
Interface accessories	From Page A-42

VISOR® V10 Solar sensor

Advanced vision sensor for wafer and cell inspection, C-mount



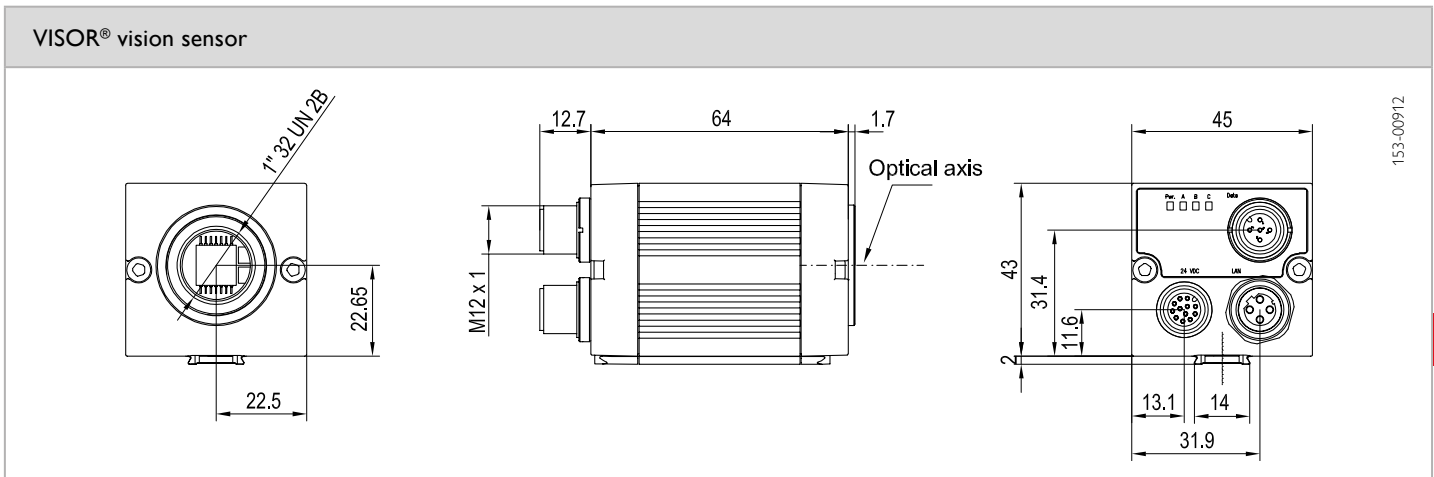
PRODUCT HIGHLIGHTS

- Automatic detection of wafer and cell geometry
- Suitable for frontlit and backlit applications
- Simple sensor optimisation regarding evaluation speed and test precision (sub-pixel process)
- Detection of holes/cracks and breakouts
- Distortion correction
- Examination and position detection of busbars

Optical data		Functions	
Resolution	736 x 480 pixels	Number of jobs / detectors	max. 255 / max. 255
CMOS	1/3", monochrome	Detectors	Wafers, pattern comparison, contrast, brightness, grey level, calliper
Integrated lens, focal length	C-Mount	Properties	Position tracking; Wafers incl. busbars: localisation of wafers or busbars and examination of wafers; Calliper: distance between edges; Pattern comparison: teach-in and detection of patterns grey threshold, brightness: evaluation of brightness; contrast: evaluation of contrast
Adjustment range	Dependent on lens	Typical cycle times	Typ. 100 ms wafer Typ. 8 ms calliper Typ. 20 ms pattern comparison Typ. 2 ms brightness Typ. 2 ms contrast Typ. 2 ms grey threshold
Integrated illumination	None		
Minimum field of view, X x Y	Dependent on lens		
Electrical data		Mechanical data	
Operating voltage, +U _B	18 ... 26.4V DC ¹	Dimensions	65 x 45 x 45 mm (without plug)
Current consumption (without illumination and I/O)	≤ 120 mA	Enclosure rating	IP 65 ²
Current consumption (without I/O)	≤ 200 mA	Material, housing	Aluminium, plastic
Protective circuits	Reverse-polarity protection, U _B / short-circuit protection of all outputs	Material, front screen	Plastic
Power On Delay	Ca. 13 s after Power on	Ambient temperature: operation	0 ... +50 °C ³
Outputs	PNP / NPN (switchable)	Ambient temperature: storage	-20 ... +60 °C ³
Max. output current (per output)	50 mA, 100 mA (pin 12)	Weight	Ca. 160 g
Inputs	PNP/NPN High > U _B -1 V, Low < 3 V	Plug connections	Supply and I/O M12, 12-pin Ethernet M12, 4-pin Data M12, 5-pin
Input resistance	> 20 kOhm	Vibration and impact resistance	EN 60947-5-2
Encoder input	High > 4 V		
Interfaces	Ethernet (LAN), RS422, RS232, EtherNet/IP, PROFINET, SensoWeb		
Inputs/outputs	2 inputs, 4 outputs, 4 selectable inputs/outputs		

¹ Max. ripple < 5V_{SS} ² With LPT45 C-mount protective casing ³ 80 % air humidity, non-condensing

Part number	Article number
V10-SO-A1-C	535-91050



	LO C 8	LO C 12	LO C 16	LO C 25	LO C 35	LO C 50	LO C 75
Focal length	8 mm	12 mm	16 mm	25 mm	35 mm	50 mm	75 mm
Article number	526-51513	526-51514	526-51515	526-51516	526-51525	526-51113	526-51116

Accessories

Connection cables	From Page A-38
Illumination	From Page A-30
Lenses	From Page A-27
Brackets	From Page A-14
Interface accessories	From Page A-42